# **Bipolar Transistor**



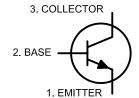


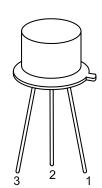
### **Description:**

This is a Silicon NPN transistor in a TO-39 type case designed primarily for amplifier and switching applications. This device features high breakdown voltage low leakage current, low capacity, and beta useful over an extremely wide current range.

## RoHS Compliant

#### **NPN**





#### **Absolute Maximum Ratings:**

Characteristic	Symbol	Rating
Collector-Base Voltage	Vсво	140V
Collector-Emitter Voltage	VCEO	80V
Emitter - Base Voltage	Vево	7V
Continuous Collector Current	Ic	1A
Total Device Dissipation (Tc = +25°C)  Derate above 25°C	Pb	800mW 4.6mW/°C
Total Device Dissipation (Tc = +25°C)  Derate above 25°C	Pb	5W 28.6mW/°C
Operating Junction Temperature Range	TJ	-65°C to +200°C
Storage Temperature Range	Тsтg	-65°C to +200°C
Thermal Resistance, Junction-to-Case	RthJC	16.5°C/W
Thermal Resistance, Junction-to-Ambient	RthJA	89.5°C/W
Lead Temperature (During Soldering, 1/16" from case, 60sec max.)	Tι	300°C

### **Electrical Characteristics:** (TA = +25°C Unless otherwise specified)

Parameter	Symbol	Test Conditions	Min.	Max.	Unit.		
OFF Characteristics							
Collector-Emitter Breakdown Voltage	V(BR)CEO	Ic = 30mA, I <sub>B</sub> = 0	80	-			
Collector-Base Breakdown Voltage	V(BR)CBO	Ic = 100μA, IE = 0	140	-	V		
Emitter-Base Breakdown Voltage	V(BR)EBO	IE = 100μA, Ic = 0	7	-	1		
0.110.100.001.0000	Ісво	V <sub>CB</sub> = 90V, I <sub>E</sub> = 0	-	0.01			
Collector-Cut-Off Current		V <sub>CB</sub> = 90V, I <sub>E</sub> = 0, T <sub>A</sub> = +150°C	-	10	μΑ		
Emitter Cut-Off Current	ІЕВО	V <sub>BE</sub> = 5V, I <sub>C</sub> = 0	-	0.01			
On Characteristics (Note 1)							
		VcE = 10V, Ic = 0.1mA	50	-	-		
DC Current Gain	hfe	VcE = 10V, Ic = 10mA	90	-	-		
		VcE = 10V, Ic = 150mA	100	300	-		

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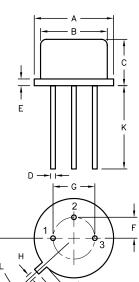


Parameter	Symbol	Test Conditions	Min.	Max.	Unit.
		VcE = 10V, Ic = 150mA, T <sub>A</sub> = -55°C	40	-	-
DC Current Gain	hfe	VcE = 10V, Ic = 500mA	50	-	-
		VcE = 10V, Ic = 1A	15	-	-
Collector Emitter Saturation Voltage	\/s=(_0	Ic = 150mA, I <sub>B</sub> = 15mA	-	0.2	V
Collector-Emitter Saturation Voltage	VCE(sat)	Ic = 150mA, I <sub>B</sub> = 50mA	-	0.5	V
Base-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	Ic = 150mA, I <sub>B</sub> = 15mA	-	1.1	V

#### **Small-Signal Characteristics**

Current Gain-Bandwidth Product	f⊤	VcE = 10V, Ic = 50mA, f = 20MHz	100	400	MHz
Output Capacitance	Cobo	Vcb = 10V, IE = 0, f = 1MHz	-	12	pF
Input Capacitance	Cibo	V <sub>BE</sub> = 500mV, I <sub>C</sub> = 0, f = 1MHz	-	60	pF
Small-Signal Current Gain	h <sub>fe</sub>	VcE = 5V, Ic = 1mA, f = 1kHz	80	400	-
Collector-Base Time Constant	rb'Cc	Vce = 10V, Ie = 10mA, f = 1kHz	-	400	ps
Noise Figure	NF	Vcε = 10V, lc = 100 μA, f = kHz, Rs = 1kΩ	-	4	dB

**Note 1.** Pulse Test: Pulse Width  $\leq 300 \mu s$ , Duty Cycle  $\leq 1\%$ 



- 1. EMITTER
- 2 BASE
- 3. COLLECTOR

Dimensions	Α	В	С	D	E	F	G	Н	J	K	L
Min.	8.5	7.74	6.09	0.4	-	2.41	4.82	0.71	0.73	12.7	42°
Max.	9.39	8.50	6.6	0.53	0.88	2.66	5.33	0.86	1.02	-	48°

Dimensions: Millimetres

#### **Part Number Table**

Description	Part Number		
Bipolar Transistor, NPN, 1A, 80V, TO-39	2N3019		

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